

74HC2G34-Q100; 74HCT2G34-Q100

Dual buffer gate

Rev. 2 — 4 November 2013

Product data sheet

1. General description

The 74HC2G34-Q100; 74HCT2G34-Q100 is a dual buffer. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of V_{CC} .

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 - ◆ Specified from $-40\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$ and from $-40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$
- Input levels:
 - ◆ For 74HC2G34-Q100: CMOS level
 - ◆ For 74HCT2G34-Q100: TTL level
- Wide supply voltage range from 2.0 V to 6.0 V
- Complies with JEDEC standard no. 7A
- High noise immunity
- ESD protection:
 - ◆ MIL-STD-883, method 3015 exceeds 2000 V
 - ◆ HBM JESD22-A114F exceeds 2000 V
 - ◆ MM JESD22-A115-A exceeds 200 V ($C = 200\text{ pF}$, $R = 0\text{ }\Omega$)
- Low power dissipation
- Balanced propagation delays
- Unlimited input rise and fall times

3. Ordering information

Table 1. Ordering information

| Type number | Package | | | |
|------------------|---|-------|--|---------|
| | Temperature range | Name | Description | Version |
| 74HC2G34GW-Q100 | $-40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$ | SC-88 | plastic surface-mounted package; 6 leads | SOT363 |
| 74HCT2G34GW-Q100 | | | | |
| 74HC2G34GV-Q100 | $-40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$ | SC-74 | plastic surface-mounted package (TSOP6); 6 leads | SOT457 |
| 74HCT2G34GV-Q100 | | | | |

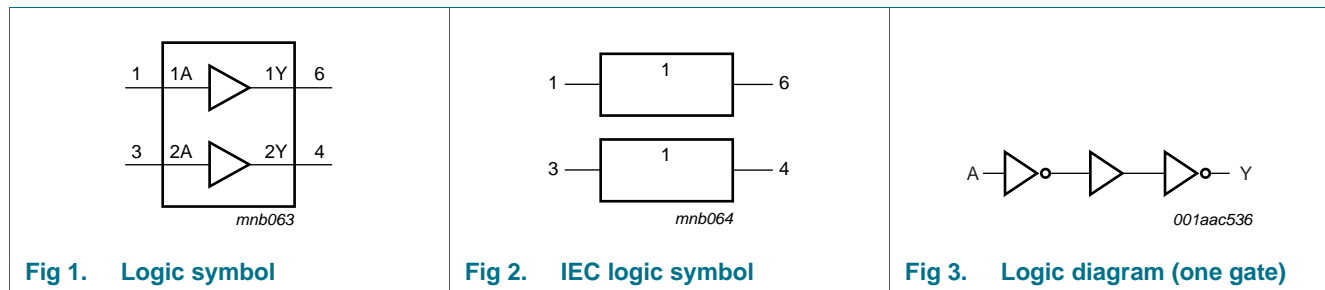
4. Marking

Table 2. Marking

| Type number | Marking code ^[1] |
|------------------|-----------------------------|
| 74HC2G34GW-Q100 | PA |
| 74HCT2G34GW-Q100 | UA |
| 74HC2G34GV-Q100 | P34 |
| 74HCT2G34GV-Q100 | U34 |

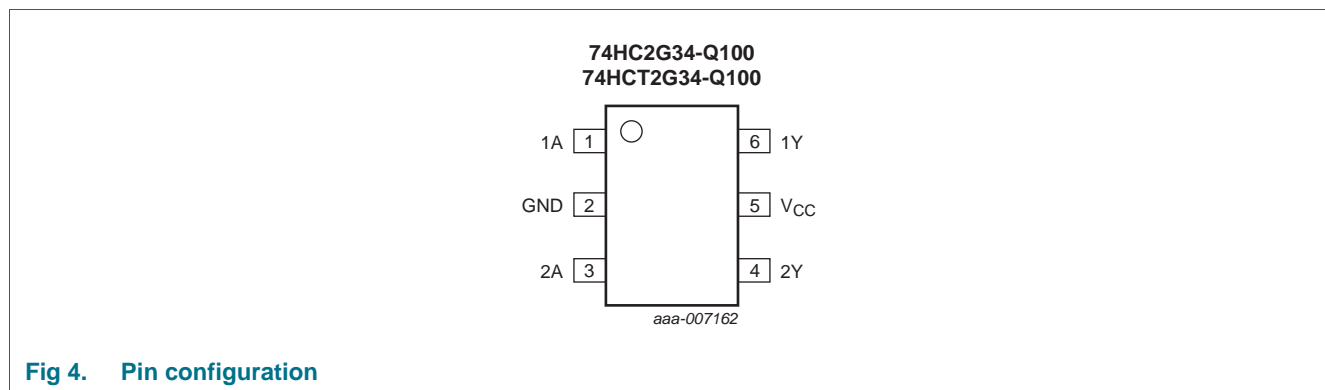
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram



6. Pinning information

6.1 Pinning



6.2 Pin description

Table 3. Pin description

| Symbol | Pin | Description |
|-----------------|-----|----------------|
| 1A | 1 | data input |
| GND | 2 | ground (0 V) |
| 2A | 3 | data input |
| 2Y | 4 | data output |
| V _{CC} | 5 | supply voltage |
| 1Y | 6 | data output |

7. Functional description

Table 4. Function table^[1]

| Input | Output |
|-------|--------|
| nA | nY |
| L | L |
| H | H |

[1] H = HIGH voltage level; L = LOW voltage level.

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|-------------------------|---|------|------|------|
| V _{CC} | supply voltage | | -0.5 | +7.0 | V |
| I _{IK} | input clamping current | V _I < -0.5 V or V _I > V _{CC} + 0.5 V | [1] | ±20 | mA |
| I _{OK} | output clamping current | V _O < -0.5 V or V _O > V _{CC} + 0.5 V | [1] | ±20 | mA |
| I _O | output current | V _O = -0.5 V to V _{CC} + 0.5 V | [1] | ±25 | mA |
| I _{CC} | supply current | | [1] | +50 | mA |
| I _{GND} | ground current | | [1] | -50 | mA |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| P _{tot} | total power dissipation | | [2] | 250 | mW |

[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SC-88 and SC-74 packages: above 87.5 °C the value of P_{tot} derates linearly with 4.0 mW/K.

9. Recommended operating conditions

Table 6. Recommended operating conditions

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|----------------------------|---------------------|-----------------------------------|-----|-----|----------|------|
| Type 74HC2G34-Q100 | | | | | | |
| V_{CC} | supply voltage | | 2.0 | 5.0 | 6.0 | V |
| V_I | input voltage | | 0 | - | V_{CC} | V |
| V_O | output voltage | | 0 | - | V_{CC} | V |
| T_{amb} | ambient temperature | | -40 | +25 | +125 | °C |
| t_r | rise time | except for Schmitt trigger inputs | | | | |
| | | $V_{CC} = 2.0\text{ V}$ | - | - | 1000 | ns |
| | | $V_{CC} = 4.5\text{ V}$ | - | - | 500 | ns |
| | | $V_{CC} = 6.0\text{ V}$ | - | - | 400 | ns |
| t_f | fall time | except for Schmitt trigger inputs | | | | |
| | | $V_{CC} = 2.0\text{ V}$ | - | - | 1000 | ns |
| | | $V_{CC} = 4.5\text{ V}$ | - | - | 500 | ns |
| | | $V_{CC} = 6.0\text{ V}$ | - | - | 400 | ns |
| Type 74HCT2G34-Q100 | | | | | | |
| V_{CC} | supply voltage | | 4.5 | 5.0 | 5.5 | V |
| V_I | input voltage | | 0 | - | V_{CC} | V |
| V_O | output voltage | | 0 | - | V_{CC} | V |
| T_{amb} | ambient temperature | | -40 | +25 | +125 | °C |
| t_r | rise time | except for Schmitt trigger inputs | | | | |
| | | $V_{CC} = 4.5\text{ V}$ | - | - | 500 | ns |
| t_f | fall time | except for Schmitt trigger inputs | | | | |
| | | $V_{CC} = 4.5\text{ V}$ | - | - | 500 | ns |

10. Static characteristics

Table 7. Static characteristics for 74HC2G34-Q100

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|--------------------------|--------------------------|-------------------------|------|-----|------|------|
| $T_{amb} = 25\text{ °C}$ | | | | | | |
| V_{IH} | HIGH-level input voltage | $V_{CC} = 2.0\text{ V}$ | 1.5 | 1.2 | - | V |
| | | $V_{CC} = 4.5\text{ V}$ | 3.15 | 2.4 | - | V |
| | | $V_{CC} = 6.0\text{ V}$ | 4.2 | 3.2 | - | V |
| V_{IL} | LOW-level input voltage | $V_{CC} = 2.0\text{ V}$ | - | 0.8 | 0.5 | V |
| | | $V_{CC} = 4.5\text{ V}$ | - | 2.1 | 1.35 | V |
| | | $V_{CC} = 6.0\text{ V}$ | - | 2.8 | 1.8 | V |

Table 7. Static characteristics for 74HC2G34-Q100 ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|---|---------------------------|---|------|------|-----------|---------------|
| V_{OH} | HIGH-level output voltage | $V_I = V_{IH}$ or V_{IL} | | | | |
| | | $I_O = -20\ \mu\text{A}; V_{CC} = 2.0\ \text{V}$ | 1.9 | 2.0 | - | V |
| | | $I_O = -20\ \mu\text{A}; V_{CC} = 4.5\ \text{V}$ | 4.4 | 4.5 | - | V |
| | | $I_O = -20\ \mu\text{A}; V_{CC} = 6.0\ \text{V}$ | 5.9 | 6.0 | - | V |
| | | $I_O = -4.0\ \text{mA}; V_{CC} = 4.5\ \text{V}$ | 4.18 | 4.32 | - | V |
| | | $I_O = -5.2\ \text{mA}; V_{CC} = 6.0\ \text{V}$ | 5.68 | 5.81 | - | V |
| V_{OL} | LOW-level output voltage | $V_I = V_{IH}$ or V_{IL} | | | | |
| | | $I_O = 20\ \mu\text{A}; V_{CC} = 2.0\ \text{V}$ | - | 0 | 0.1 | V |
| | | $I_O = 20\ \mu\text{A}; V_{CC} = 4.5\ \text{V}$ | - | 0 | 0.1 | V |
| | | $I_O = 20\ \mu\text{A}; V_{CC} = 6.0\ \text{V}$ | - | 0 | 0.1 | V |
| | | $I_O = 4.0\ \text{mA}; V_{CC} = 4.5\ \text{V}$ | - | 0.15 | 0.26 | V |
| | | $I_O = 5.2\ \text{mA}; V_{CC} = 6.0\ \text{V}$ | - | 0.16 | 0.26 | V |
| I_I | input leakage current | $V_I = \text{GND}$ or $V_{CC}; V_{CC} = 6.0\ \text{V}$ | - | - | ± 0.1 | μA |
| I_{CC} | supply current | $V_I = \text{GND}$ or $V_{CC}; I_O = 0\ \text{A}; V_{CC} = 6.0\ \text{V}$ | - | - | 1.0 | μA |
| C_I | input capacitance | | - | 1.5 | - | pF |
| $T_{amb} = -40\ ^\circ\text{C}$ to $+85\ ^\circ\text{C}$ | | | | | | |
| V_{IH} | HIGH-level input voltage | $V_{CC} = 2.0\ \text{V}$ | 1.5 | - | - | V |
| | | $V_{CC} = 4.5\ \text{V}$ | 3.15 | - | - | V |
| | | $V_{CC} = 6.0\ \text{V}$ | 4.2 | - | - | V |
| V_{IL} | LOW-level input voltage | $V_{CC} = 2.0\ \text{V}$ | - | - | 0.5 | V |
| | | $V_{CC} = 4.5\ \text{V}$ | - | - | 1.35 | V |
| | | $V_{CC} = 6.0\ \text{V}$ | - | - | 1.8 | V |
| V_{OH} | HIGH-level output voltage | $V_I = V_{IH}$ or V_{IL} | | | | |
| | | $I_O = -20\ \mu\text{A}; V_{CC} = 2.0\ \text{V}$ | 1.9 | - | - | V |
| | | $I_O = -20\ \mu\text{A}; V_{CC} = 4.5\ \text{V}$ | 4.4 | - | - | V |
| | | $I_O = -20\ \mu\text{A}; V_{CC} = 6.0\ \text{V}$ | 5.9 | - | - | V |
| | | $I_O = -4.0\ \text{mA}; V_{CC} = 4.5\ \text{V}$ | 4.13 | - | - | V |
| | | $I_O = -5.2\ \text{mA}; V_{CC} = 6.0\ \text{V}$ | 5.63 | - | - | V |
| V_{OL} | LOW-level output voltage | $V_I = V_{IH}$ or V_{IL} | | | | |
| | | $I_O = 20\ \mu\text{A}; V_{CC} = 2.0\ \text{V}$ | - | - | 0.1 | V |
| | | $I_O = 20\ \mu\text{A}; V_{CC} = 4.5\ \text{V}$ | - | - | 0.1 | V |
| | | $I_O = 20\ \mu\text{A}; V_{CC} = 6.0\ \text{V}$ | - | - | 0.1 | V |
| | | $I_O = 4.0\ \text{mA}; V_{CC} = 4.5\ \text{V}$ | - | - | 0.33 | V |
| | | $I_O = 5.2\ \text{mA}; V_{CC} = 6.0\ \text{V}$ | - | - | 0.33 | V |
| I_I | input leakage current | $V_I = \text{GND}$ or $V_{CC}; V_{CC} = 6.0\ \text{V}$ | - | - | ± 1.0 | μA |
| I_{CC} | supply current | $V_I = \text{GND}$ or $V_{CC}; I_O = 0\ \text{A}; V_{CC} = 6.0\ \text{V}$ | - | - | 10.0 | μA |

Table 7. Static characteristics for 74HC2G34-Q100 ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|--|---------------------------|--|------|-----|------|------|
| T_{amb} = -40 °C to +125 °C | | | | | | |
| V _{IH} | HIGH-level input voltage | V _{CC} = 2.0 V | 1.5 | - | - | V |
| | | V _{CC} = 4.5 V | 3.15 | - | - | V |
| | | V _{CC} = 6.0 V | 4.2 | - | - | V |
| V _{IL} | LOW-level input voltage | V _{CC} = 2.0 V | - | - | 0.5 | V |
| | | V _{CC} = 4.5 V | - | - | 1.35 | V |
| | | V _{CC} = 6.0 V | - | - | 1.8 | V |
| V _{OH} | HIGH-level output voltage | V _I = V _{IH} or V _{IL} | | | | |
| | | I _O = -20 μA; V _{CC} = 2.0 V | 1.9 | - | - | V |
| | | I _O = -20 μA; V _{CC} = 4.5 V | 4.4 | - | - | V |
| | | I _O = -20 μA; V _{CC} = 6.0 V | 5.9 | - | - | V |
| | | I _O = -4.0 mA; V _{CC} = 4.5 V | 3.7 | - | - | V |
| V _{OL} | LOW-level output voltage | V _I = V _{IH} or V _{IL} | | | | |
| | | I _O = 20 μA; V _{CC} = 2.0 V | - | - | 0.1 | V |
| | | I _O = 20 μA; V _{CC} = 4.5 V | - | - | 0.1 | V |
| | | I _O = 20 μA; V _{CC} = 6.0 V | - | - | 0.1 | V |
| | | I _O = 4.0 mA; V _{CC} = 4.5 V | - | - | 0.4 | V |
| | | I _O = 5.2 mA; V _{CC} = 6.0 V | - | - | 0.4 | V |
| I _I | input leakage current | V _I = GND or V _{CC} ; V _{CC} = 6.0 V | - | - | ±1.0 | μA |
| I _{CC} | supply current | V _I = GND or V _{CC} ; I _O = 0 A; V _{CC} = 6.0 V | - | - | 20.0 | μA |

Table 8. Static characteristics for 74HCT2G34-Q100

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|--------------------------------|---------------------------|---|------|------|------|------|
| T_{amb} = 25 °C | | | | | | |
| V _{IH} | HIGH-level input voltage | V _{CC} = 4.5 V to 5.5 V | 2.0 | 1.6 | - | V |
| V _{IL} | LOW-level input voltage | V _{CC} = 4.5 V to 5.5 V | - | 1.2 | 0.8 | V |
| V _{OH} | HIGH-level output voltage | V _I = V _{IH} or V _{IL} | | | | |
| | | I _O = -20 μA; V _{CC} = 4.5 V | 4.4 | 4.5 | - | V |
| | | I _O = -4.0 mA; V _{CC} = 4.5 V | 4.18 | 4.32 | - | V |
| V _{OL} | LOW-level output voltage | V _I = V _{IH} or V _{IL} | | | | |
| | | I _O = 20 μA; V _{CC} = 4.5 V | - | 0 | 0.1 | V |
| | | I _O = 4.0 mA; V _{CC} = 4.5 V | - | 0.15 | 0.26 | V |
| I _I | input leakage current | V _I = GND or V _{CC} ; V _{CC} = 5.5 V | - | - | ±0.1 | μA |
| I _{CC} | supply current | V _I = GND or V _{CC} ; I _O = 0 A; V _{CC} = 5.5 V | - | - | 1.0 | μA |
| ΔI _{CC} | additional supply current | V _I = V _{CC} - 2.1 V; V _{CC} = 4.5 V to 5.5 V; I _O = 0 A | - | - | 300 | μA |
| C _I | input capacitance | | - | 1.5 | - | pF |

Table 8. Static characteristics for 74HCT2G34-Q100 ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|---|---------------------------|--|------|-----|-----------|---------------|
| $T_{amb} = -40\text{ °C to }+85\text{ °C}$ | | | | | | |
| V_{IH} | HIGH-level input voltage | $V_{CC} = 4.5\text{ V to }5.5\text{ V}$ | 2.0 | - | - | V |
| V_{IL} | LOW-level input voltage | $V_{CC} = 4.5\text{ V to }5.5\text{ V}$ | - | - | 0.8 | V |
| V_{OH} | HIGH-level output voltage | $V_I = V_{IH}\text{ or }V_{IL}$ | | | | |
| | | $I_O = -20\text{ }\mu\text{A}; V_{CC} = 4.5\text{ V}$ | 4.4 | - | - | V |
| | | $I_O = -4.0\text{ mA}; V_{CC} = 4.5\text{ V}$ | 4.13 | - | - | V |
| V_{OL} | LOW-level output voltage | $V_I = V_{IH}\text{ or }V_{IL}$ | | | | |
| | | $I_O = 20\text{ }\mu\text{A}; V_{CC} = 4.5\text{ V}$ | - | - | 0.1 | V |
| | | $I_O = 4.0\text{ mA}; V_{CC} = 4.5\text{ V}$ | - | - | 0.33 | V |
| I_I | input leakage current | $V_I = \text{GND or }V_{CC}; V_{CC} = 5.5\text{ V}$ | - | - | ± 1.0 | μA |
| I_{CC} | supply current | $V_I = \text{GND or }V_{CC}; I_O = 0\text{ A}; V_{CC} = 5.5\text{ V}$ | - | - | 10.0 | μA |
| ΔI_{CC} | additional supply current | $V_I = V_{CC} - 2.1\text{ V}; V_{CC} = 4.5\text{ V to }5.5\text{ V}; I_O = 0\text{ A}$ | - | - | 375 | μA |
| $T_{amb} = -40\text{ °C to }+125\text{ °C}$ | | | | | | |
| V_{IH} | HIGH-level input voltage | $V_{CC} = 4.5\text{ V to }5.5\text{ V}$ | 2.0 | - | - | V |
| V_{IL} | LOW-level input voltage | $V_{CC} = 4.5\text{ V to }5.5\text{ V}$ | - | - | 0.8 | V |
| V_{OH} | HIGH-level output voltage | $V_I = V_{IH}\text{ or }V_{IL}$ | | | | |
| | | $I_O = -20\text{ }\mu\text{A}; V_{CC} = 4.5\text{ V}$ | 4.4 | - | - | V |
| | | $I_O = -4.0\text{ mA}; V_{CC} = 4.5\text{ V}$ | 3.7 | - | - | V |
| V_{OL} | LOW-level output voltage | $V_I = V_{IH}\text{ or }V_{IL}$ | | | | |
| | | $I_O = 20\text{ }\mu\text{A}; V_{CC} = 4.5\text{ V}$ | - | - | 0.1 | V |
| | | $I_O = 4.0\text{ mA}; V_{CC} = 4.5\text{ V}$ | - | - | 0.4 | V |
| I_I | input leakage current | $V_I = \text{GND or }V_{CC}; V_{CC} = 5.5\text{ V}$ | - | - | ± 1.0 | μA |
| I_{CC} | supply current | $V_I = \text{GND or }V_{CC}; I_O = 0\text{ A}; V_{CC} = 5.5\text{ V}$ | - | - | 20.0 | μA |
| ΔI_{CC} | additional supply current | $V_I = V_{CC} - 2.1\text{ V}; V_{CC} = 4.5\text{ V to }5.5\text{ V}; I_O = 0\text{ A}$ | - | - | 410 | μA |

11. Dynamic characteristics

Table 9. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see [Figure 6](#).

| Symbol | Parameter | Conditions | 25 °C | | | -40 °C to +125 °C | | | Unit |
|-----------------------|-------------------------------|--|-------|-----|-----|-------------------|-------------|--------------|------|
| | | | Min | Typ | Max | Min | Max (85 °C) | Max (125 °C) | |
| 74HC2G34-Q100 | | | | | | | | | |
| t_{pd} | propagation delay | nA to nY; see Figure 5 [1] | | | | | | | |
| | | $V_{CC} = 2.0\text{ V}; C_L = 50\text{ pF}$ | - | 29 | 75 | - | 95 | 125 | ns |
| | | $V_{CC} = 4.5\text{ V}; C_L = 50\text{ pF}$ | - | 9 | 15 | - | 19 | 25 | ns |
| | | $V_{CC} = 6.0\text{ V}; C_L = 50\text{ pF}$ | - | 8 | 13 | - | 16 | 20 | ns |
| t_t | transition time | nY; see Figure 5 [2] | | | | | | | |
| | | $V_{CC} = 2.0\text{ V}; C_L = 50\text{ pF}$ | - | 18 | 75 | - | 95 | 125 | ns |
| | | $V_{CC} = 4.5\text{ V}; C_L = 50\text{ pF}$ | - | 6 | 15 | - | 19 | 25 | ns |
| | | $V_{CC} = 6.0\text{ V}; C_L = 50\text{ pF}$ | - | 5 | 13 | - | 16 | 20 | ns |
| C_{PD} | power dissipation capacitance | $V_I = \text{GND to } V_{CC}$ [3] | - | 10 | - | - | - | - | pF |
| 74HCT2G34-Q100 | | | | | | | | | |
| t_{pd} | propagation delay | nA to nY; see Figure 5 [1] | | | | | | | |
| | | $V_{CC} = 4.5\text{ V}; C_L = 50\text{ pF}$ | - | 10 | 18 | - | 23 | 29 | ns |
| t_t | transition time | nY; see Figure 5 [2] | | | | | | | |
| | | $V_{CC} = 4.5\text{ V}; C_L = 50\text{ pF}$ | - | 6 | 15 | - | 19 | 25 | ns |
| C_{PD} | power dissipation capacitance | $V_I = \text{GND to } V_{CC} - 1.5\text{ V}$ [3] | - | 9 | - | - | - | - | pF |

[1] t_{pd} is the same as t_{PLH} and t_{PHL}

[2] t_t is the same as t_{TLH} and t_{THL}

[3] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

f_i = input frequency in MHz;

f_o = output frequency in MHz;

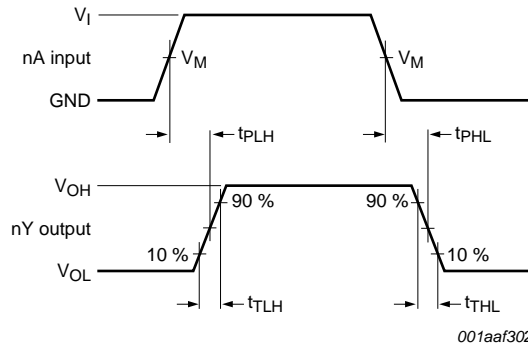
C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

$\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

12. Waveforms



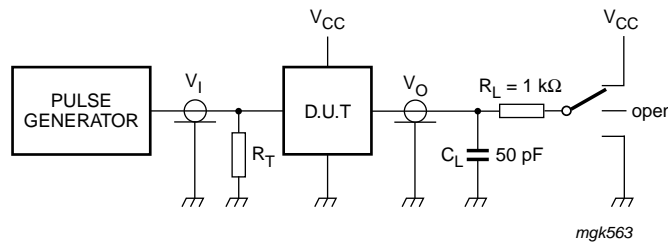
Measurement points are given in [Table 10](#).

V_{OL} and V_{OH} are typical voltage output levels that occur with the output load.

Fig 5. The data input (nA) to output (nY) propagation delays and output transition times

Table 10. Measurement points

| Type | Input | | | Output |
|----------------|-------------|-----------------|-------------|-------------|
| | V_M | V_I | $t_r = t_f$ | V_M |
| 74HC2G34-Q100 | $0.5V_{CC}$ | GND to V_{CC} | 6.0 ns | $0.5V_{CC}$ |
| 74HCT2G34-Q100 | 1.3 V | GND to 3.0 V | 6.0 ns | 1.3 V |



Test data is given in [Table 11](#).

Definitions test circuit:

R_L = Load resistance.

C_L = Load capacitance including jig and probe capacitance.

R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator.

Fig 6. Test circuit for measuring switching times

Table 11. Test data

| Type | Input | | Test |
|----------------|-----------------|------------|--------------------|
| | V_I | t_r, t_f | t_{PHL}, t_{PLH} |
| 74HC2G34-Q100 | GND to V_{CC} | 6 ns | open |
| 74HCT2G34-Q100 | GND to 3.0 V | 6 ns | open |

13. Package outline

Plastic surface-mounted package; 6 leads

SOT363

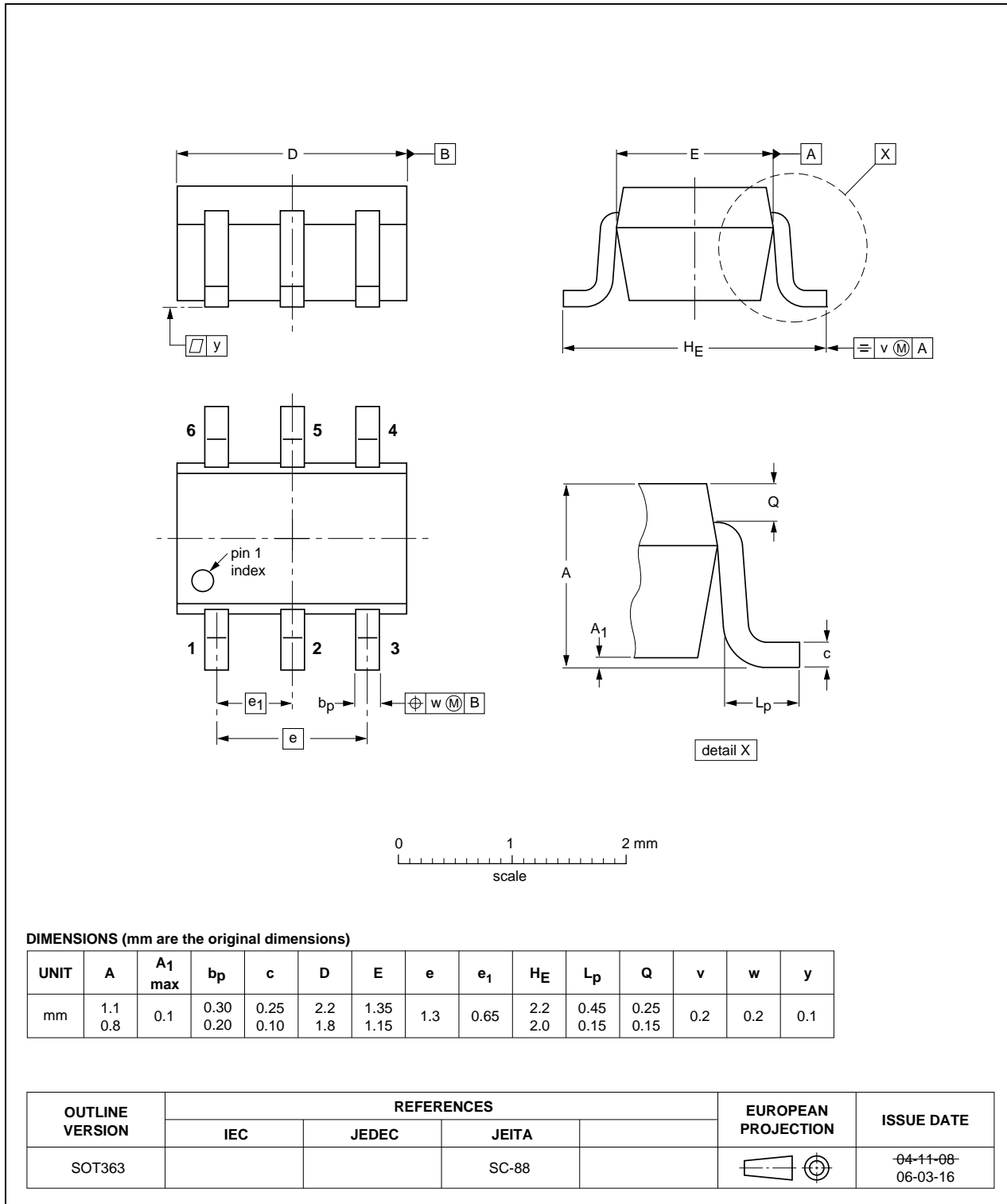


Fig 7. Package outline SOT363 (SC-88)

Plastic surface-mounted package (TSOP6); 6 leads

SOT457

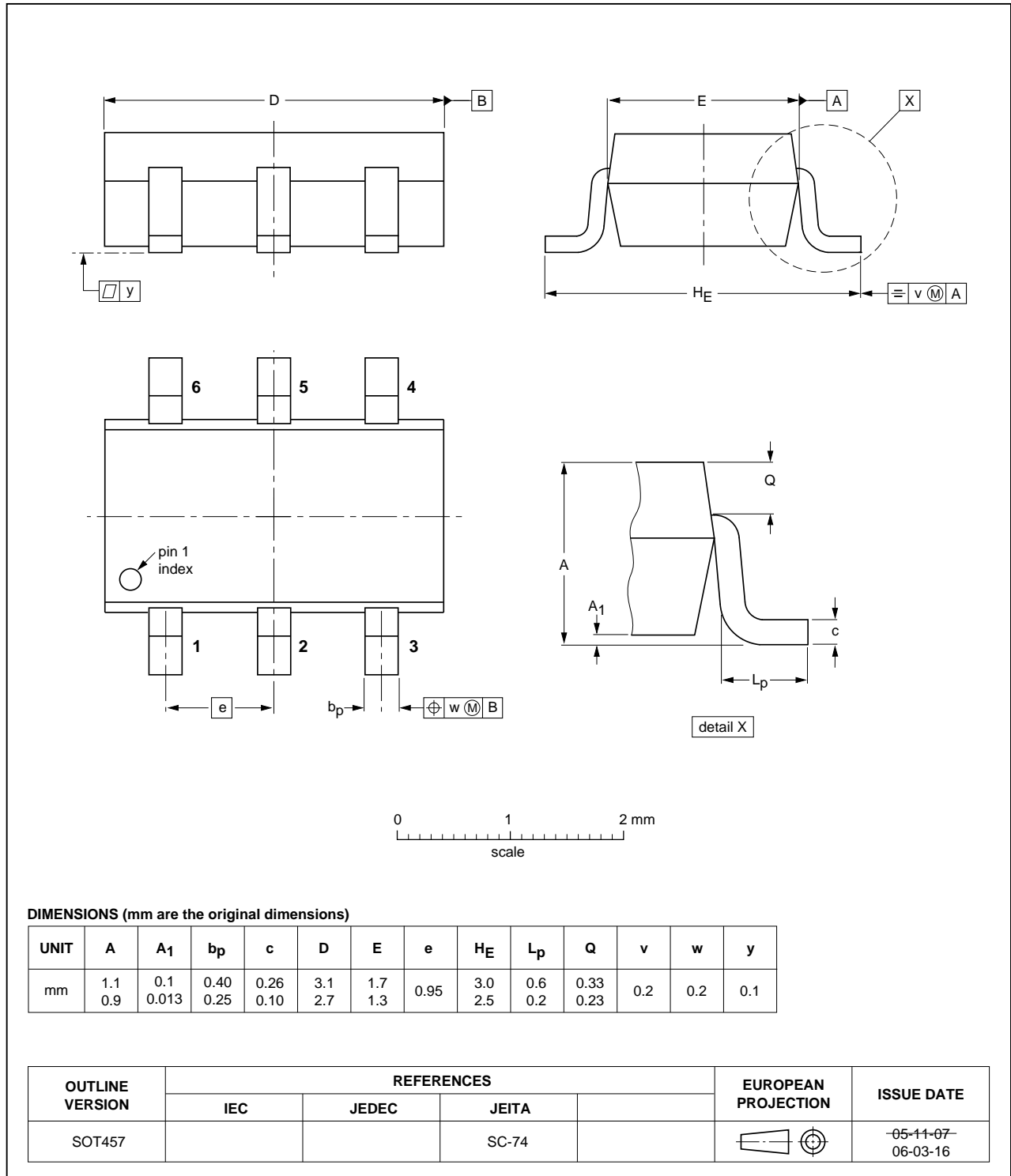


Fig 8. Package outline SOT457 (SC-74)

14. Abbreviations

Table 12. Abbreviations

| Acronym | Description |
|---------|---|
| CMOS | Complementary Metal Oxide Semiconductor |
| ESD | ElectroStatic Discharge |
| HBM | Human Body Model |
| MIL | Military |
| MM | Machine Model |
| DUT | Device Under Test |

15. Revision history

Table 13. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|-----------------------|---|--------------------|---------------|-----------------------|
| 74HC_HCT2G34_Q100 v.2 | 20131104 | Product data sheet | - | 74HC_HCT2G34_Q100 v.1 |
| Modifications: | <ul style="list-style-type: none"> Added type number 74HC2G34GW and 74HCT2G34GW (SOT363) | | | |
| 74HC_HCT2G34_Q100 v.1 | 20130417 | Product data sheet | - | - |

16. Legal information

16.1 Data sheet status

| Document status ^{[1][2]} | Product status ^[3] | Definition |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nexperia.com>.

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